NSN 5961-01-380-3738

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-380-3738 **Inclosure Material:** Plastic **Overall Length:** 3.700 inches **Overall Height:** 1.220 inches **Overall Width:** 1.340 inches **Function For Which Designed:** Switching **End Application:** Tarawa class lha; spruance class dd (963); arleigh burke class ddg; forrestal class cv; nimitz class cvn; ticonderoga class cg (47); oliver perry class ffg; supply class aoe; wasp class lhd **Mounting Facility Quantity: Component Name And Quantity:** 2 semiconductor device diode and 2 transistor **Mounting Method:** Unthreaded hole **Overall Width Across Flats:** 3.800 inches **Semiconductor Material:** Silicon single semiconductor Voltage Rating In Volts Per Characteristic: 600.0 collector-to-emitter, substaining voltage, base short-circuitedto emitter single semiconductor **Current Rating Per Characteristic:** 100.00 amperes repetitive peak forward current blank single semiconductor **Power Rating Per Characteristic:** 400.0 watts small-signal input power, common-collector absolute single semiconductor **Terminal Type And Quantity:** 3 screw and 4 tab, solder lug Shelf Life: N/a **Unit Of Measure:** Demilitarization: No